Post-processing techniques in electronic structure calculations with DFTK.jl

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Discrete formulation of KS-DFT

Mathematical formulation Optimality conditions

Post-processing techniques for KS-DFT: error estimates and refinement

Computational framework and linearization Error bounds for interatomic forces based on linearization

Implementation in DFTK.jl

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General framework

We seek the ground-state energy and density by solving a constrained minimization problem:

$$E(P) := \operatorname{Tr}(H_0P) + \frac{E_{nl}(P)}{nonlinear term}$$

- ▶ $P \in \mathbb{C}_{herm}^{N \times N}$ is a trial density matrix;
- N is the dimension of the approximation space (linked to the cut-off energy E_{cut} in DFTK.jl);
- $H_0 = -\frac{1}{2}\Delta + V$ is the core Hamiltonian;
- *E*_{nl} models the electron-electron interaction, depending on the chosen DFT model.

Kohn–Sham equations with LDA

Obtained as the Euler–Lagrange equations of (1):

$$\begin{cases} \underbrace{(-\frac{1}{2}\Delta + V_{\text{nuc}})}_{\text{Vel}} \varphi_n + \underbrace{V_{\text{Hxc}}(\rho)}_{\text{Hxc}} \varphi_n = \varepsilon_n \varphi_n, \\ \langle \varphi_n, \varphi_m \rangle = \delta_{nm}, & & & \\ \rho = \sum_{n=1}^{N_{\text{el}}} |\varphi_n|^2. \end{cases}$$

$$\min_{P \in \mathcal{M}_{N_{el}}} E(P) = \operatorname{Tr}(H_0 P) + E_{nl}(P),$$
$$\mathcal{M}_{N_{el}} \coloneqq \left\{ P \in \mathbb{C}^{N \times N} \mid P = P^*, \ \operatorname{Tr}(P) = N_{el}, \ P^2 = P \right\}.$$

Geometrical aspects – First-order condition

 $\min_{P \in \mathcal{M}_{N_{el}}} E(P) = \operatorname{Tr} (H_0 P) + E_{nl}(P)$

The first-order optimality condition is $R(P_{\star}) := \nabla_{\mathcal{M}_{N_{el}}} E(P_{\star}) = \Pi_{P_{\star}}(H_{\star}) = 0$, which gives, with $H_{\star} = H(P_{\star})$,

$$P_{\star}H_{\star}(1-P_{\star})=(1-P_{\star})H_{\star}P_{\star}=0.$$



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• $[H_{\star}, P_{\star}] = 0 \Rightarrow H_{\star}$ and P_{\star} can be codiagonalized;

- if (φ_i)_{1≤i≤N_{el}} is an o.n.b. of eigenvectors of H_{*} ordered by nondecreasing eigenvalues, then $P_* = \sum_{i \in \mathcal{I}} φ_i φ_i^*, \text{ with } \mathcal{I} \text{ the set of occupied orbitals;}$
- $\begin{array}{l} \blacktriangleright \ \mathcal{I} \subset \{1, \ldots, N_{\rm el}\} \ {\rm and} \ |\mathcal{I}| = N_{\rm el}: \\ \begin{tabular}{l} \blacktriangleright \ \mathcal{I} = \{1, \ldots, N_{\rm el}\}: \ Aufbau \ {\rm principle}; \\ \begin{tabular}{l} \mathcal{I} = \{1, \ldots, N_{\rm el}\}: \ {\rm Aufbau} \ {\rm principle}. \end{array}$

In the decomposition $\mathcal{H} = \operatorname{Ran}(P_{\star}) \oplus \operatorname{Ran}(1 - P_{\star})$, assuming the Aufbau principle

$$H_{\star} = \begin{bmatrix} \leftarrow & \mathcal{I} & \to & \overline{\mathcal{I}} \\ \varepsilon_{1} & & & \\ & \cdot & & & \\ & & \ddots & & 0 \\ & & & \varepsilon_{N_{el}} & \\ & & & & \ddots \end{bmatrix}, P_{\star} = \begin{bmatrix} 1_{N_{el}} & 0 \\ 0 & 0 \end{bmatrix}$$

Geometrical aspects – Second-order condition

 $\min_{P \in \mathcal{M}_{N_{\text{el}}}} E(P) = \operatorname{Tr}(hP) + E_{nl}(P)$

The second-order optimality condition reads (under reasonable assumptions)

 $\left| \forall X \in \mathcal{T}_{\mathcal{P}_{\star}}\mathcal{M}_{N_{\text{el}}}, \ \left\langle X, [\boldsymbol{D}_{\mathcal{M}_{N_{\text{el}}}}^{2}\boldsymbol{E}(\boldsymbol{P}_{\star})]X \right\rangle_{\mathsf{F}} \geq \eta \, \|X\|_{\mathsf{F}}^{2}, \quad \text{with} \quad \boldsymbol{D}_{\mathcal{M}_{N_{\text{el}}}}^{2}\boldsymbol{E}(\boldsymbol{P}_{\star}) = (\boldsymbol{\Omega}_{\star} + \boldsymbol{K}_{\star})$

• $K_{\star} = \prod_{P_{\star}} \nabla^2 E(P_{\star}) \prod_{P_{\star}}$ is the classical Hessian;

▶ the operator $\Omega_{\star} : \mathcal{T}_{P_{\star}} \mathcal{M}_{N_{el}} \to \mathcal{T}_{P_{\star}} \mathcal{M}_{N_{el}}$ is defined by,

 $\forall X \in \mathcal{T}_{P_{\star}}\mathcal{M}_{N_{el}}, \quad \mathbf{\Omega}_{\star}(X) \coloneqq -[P_{\star}, [\nabla E(P_{\star}), X]].$

► $D^2_{\mathcal{M}_{N_{el}}} E(P_{\star}) = \Omega_{\star} + K_{\star}$ can be interpreted as the Hessian of the energy on the manifold, Ω_{\star} represents the influence of the curvature. Can also be seen as the Hessian of the Lagrangian.

Structure of Ω_{\star}

Let $(\varphi_i, \varepsilon_i)_{1 \leq i \leq N_{el}}$ be an eigendecomposition of H_* . Recall, if $\mathcal{H} = \operatorname{Ran}(P_*) \oplus \operatorname{Ran}(1 - P_*)$,

$$P_{\star} = \begin{bmatrix} \mathbf{1}_{N_{\text{el}}} & \mathbf{0} \\ \mathbf{0} & \mathbf{0} \end{bmatrix} \quad \text{and} \quad \mathcal{T}_{P}\mathcal{M}_{N_{\text{el}}} \coloneqq \left\{ X = \begin{bmatrix} \mathbf{0} & \times^{*} \\ \times & \mathbf{0} \end{bmatrix} \right\}.$$

Then

- ▶ for $i \in \mathcal{I}$ and $a \notin \mathcal{I}$ $(\Omega_* X)_{i_2} = (\varepsilon_a - \varepsilon_i) X_{i_2}$ and $(\Omega_* X)_{ai} = (\varepsilon_a - \varepsilon_i) X_{ai_i}$
- ▶ the gap $\min_{a \notin I} \varepsilon_a \max_{i \in I} \varepsilon_i$ is the smallest eigenvalue of Ω_* .

Remark 1: if the Aufbau principle is satisfied, then the gap is $\varepsilon_{N_{el}+1} - \varepsilon_{N_{el}}$.

Remark 2: $\Omega_{\star} = -\chi_0^{-1}$, the 4pt-independent particle susceptibility operator¹.

¹used in response calculations in DFTK.jl, cf. E. Cancès, Eric, M.F. Herbst, G. Kemlin, A. Levitt, and B. Stamm. *Numerical Stability and Efficiency of Response Property Calculations in Density Functional Theory*. Letters in Mathematical Physics 113(1):21 (2023).

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Computational framework

We consider a hierarchy of two discretization spaces with $N \ll N_{ref}$:



The problem becomes:

$$\min_{P \in \mathcal{M}_{N_{\text{el}},N}} \operatorname{Tr}(hP) + E_{\text{nl}}(P), \quad \mathcal{M}_{N_{\text{el}},N} \coloneqq \left\{ P \in \mathbb{C}^{N \times N} \mid P = P^*, \ \operatorname{Tr}(P) = N_{\text{el}}, \ P^2 = P \right\}.$$

- For convergence analysis and standard computations (ground-state energy and density, response calculations, ...), we work in V_N.
- For error estimation :
 - 1. we find a solution $P \in \mathcal{M}_{N_{el},N} \subset \mathbb{C}^{N \times N} \subset \mathbb{C}^{N_{ref} \times N_{ref}}$ in the approximation space \mathcal{V}_N (for instance with a SCF algorithm);
 - 2. we try to estimate the error w.r.t. $P_{\star} \in \mathcal{M}_{N_{el},N_{ref}} \subset \mathbb{C}^{N_{ref} \times N_{ref}}$, the solution in the reference space $\mathcal{V}_{N_{ref}}$, for a computational cost at most equivalent as for obtaining P.

Linearization

Recall that $\Omega_{\star} + K_{\star} \in \mathcal{L}(\mathcal{T}_{P_{\star}}\mathcal{M}_{N_{\text{el}},N_{\text{ref}}})$ is the Jacobian of $P \mapsto R(P) = \prod_{P} \nabla E(P)$ at P_{\star} : $\prod_{P} \nabla E(P) \approx \prod_{P_{\star}} \nabla E(P_{\star}) + (\Omega_{\star} + K_{\star})(P - P_{\star}) + o(||P - P_{\star}||_{F}).$

As $\Pi_{P_{\star}} \nabla E(P_{\star}) = 0$, with R(P) the residual, in the linear regime,

 $\Pi_P(P-P_\star)pprox (oldsymbol{\Omega}_\star+oldsymbol{\kappa}_\star)^{-1}R(P)$

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As $\Pi_{P_{\star}} \nabla E(P_{\star}) = 0$, with R(P) the residual, in the linear regime,

$$\Pi_P(P-P_\star) \approx (\mathbf{\Omega}_\star + \mathbf{K}_\star)^{-1} R(P)$$

Numerical check: the linear regime is established if $P - (\Omega_{\star} + K_{\star})^{-1}R(P)$ is much closer to P_{\star} .



Interatomic forces (at the discrete level)

Recall $E(P) = \text{Tr}(hP) + E_{nl}(P)$ with $h = -\frac{1}{2}\Delta + V$: V = V(X) for $X = (X_j) \in \omega^M$ positions of atomic nuclei $\Rightarrow E(P) = E(X, P)$.

Hellmann–Feynman:

$$P_{\star} = \operatorname{argmin} \left\{ E(X_{0}, \tilde{P}) \mid \tilde{P} \in \mathcal{M}_{N_{el}, N_{ref}} \right\};$$

$$F_{\star} = F(P_{\star}) = \left[-\nabla_{X_{j\alpha}} E(X_{0}, P_{\star}) \right]_{j=1, \dots, M}^{\alpha=1, 2, 3} = \left[-\operatorname{Tr} \left(\partial_{X_{j\alpha}} V(X_{0}) P_{\star} \right) \right]_{j=1, \dots, M}^{\alpha=1, 2, 3}.$$

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First naive error bound for the interatomic forces F(P):

$$\begin{split} |F(P) - F_{\star}| &\leq \|\mathsf{d}F(P_{\star})\|_{\mathsf{op}} \|P - P_{\star}\|_{\mathsf{F}} \\ &\leq \|\mathsf{d}F(P_{\star})\|_{\mathsf{op}} \|(\boldsymbol{\Omega}_{\star} + \boldsymbol{K}_{\star})^{-1}\|_{\mathsf{op}} \|R(P)\|_{\mathsf{F}}. \end{split}$$

Error on the forces for a silicon crystal.



In the asymptotic regime:

Replace the error
$$F(P) - F_{\star}$$
 by $dF(P) \cdot (\prod_{P}(P - P_{\star}))$.
 $\sim \circ$ Good, but not usable in practice $(P_{\star}$ is unknown).
 $(D - P_{\star}) = (P - P_{\star})$

 $E_{\rm cut}$

In the asymptotic regime:

$$\begin{array}{c} P - P_{\star} \\ \hline not \ computable \end{array} \approx \begin{array}{c} (\Omega + \mathcal{K})^{-1}R(P) \\ \hline \end{pmatrix} \approx \begin{array}{c} \mathcal{M}^{-1}R(P) \\ \hline \\ computable \end{array} \qquad \begin{array}{c} \text{in energy norm.} \\ \hline \\ computable \ and \ cheap \end{array}$$

Replace the error $F(P) - F_{\star}$ by $dF(P) \cdot (\prod_{P} (P - P_{\star}))$.

 \rightsquigarrow Good, but not usable in practice (P_{\star} is unknown).

Replace
$$P - P_{\star}$$
 by $M^{-1}R(P)$, with $M \sim -\frac{1}{2}\Delta + 1$.

→ Better, but still not satisfying.



Frequency splitting

Let $P \in \mathcal{M}_{N_{el},N_{ref}}$, then $\mathcal{T}_P \mathcal{M}_{N_{el},N_{ref}}$ can be split into low and high frequencies:

$$\mathcal{T}_{\mathcal{P}}\mathcal{M}_{N_{\text{el}},N_{\text{ref}}} = \prod_{N} \mathcal{T}_{\mathcal{P}}\mathcal{M}_{N_{\text{el}},N_{\text{ref}}} \oplus \prod_{N}^{\perp} \mathcal{T}_{\mathcal{P}}\mathcal{M}_{N_{\text{el}},N_{\text{ref}}}.$$

$$\downarrow \text{low frequencies} \uparrow \qquad \uparrow \text{high frequencies}$$

If P is a solution of the variational problem in \mathcal{V}_N , then $R(P), M^{-1}R(P) \in \prod_N^{\perp} \mathcal{T}_P \mathcal{M}_{N_{el},N_{ref}}$.



 \rightsquigarrow d*F*(*P*) is mainly supported on low frequencies.

Enhanced error bounds

We decompose the error/residual relation onto $\Pi_N \mathcal{T}_P \mathcal{M}_{N_{el},N_{ref}} \oplus \Pi_N^{\perp} \mathcal{T}_P \mathcal{M}_{N_{el},N_{ref}}$ to get

 $\begin{bmatrix} (\mathbf{\Omega} + \mathbf{K})_{11} & (\mathbf{\Omega} + \mathbf{K})_{12} \\ (\mathbf{\Omega} + \mathbf{K})_{21} & (\mathbf{\Omega} + \mathbf{K})_{22} \end{bmatrix} \begin{bmatrix} P_1 - P_{*1} \\ P_2 - P_{*2} \end{bmatrix} = \begin{bmatrix} R_1 \\ R_2 \end{bmatrix}.$

As the kinetic energy is dominating for high-frequencies, we approximate

 $(\mathbf{\Omega} + \mathbf{K})_{21} pprox 0$ and $(\mathbf{\Omega} + \mathbf{K})_{22} pprox \mathbf{M}_{22},$

and thus

$$\begin{bmatrix} (\mathbf{\Omega} + \mathbf{K})_{11} & (\mathbf{\Omega} + \mathbf{K})_{12} \\ 0 & \mathbf{M}_{22} \end{bmatrix} \begin{bmatrix} P_1 - P_{*1} \\ P_2 - P_{*2} \end{bmatrix} = \begin{bmatrix} R_1 \\ R_2 \end{bmatrix}$$

This yields a new residual, which requires only an inversion on the coarse grid (M_{22} being easy to invert):

$$R_{\text{Schur}}(P) = \begin{bmatrix} (\mathbf{\Omega} + \mathbf{K})_{11}^{-1} (R_1 - (\mathbf{\Omega} + \mathbf{K})_{12} \mathbf{M}_{22}^{-1} R_2) \\ \mathbf{M}_{22}^{-1} R_2 \end{bmatrix}$$



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Conclusion and take-home messages

- \blacktriangleright With planewaves, the asymptotic regime is quickly established \Rightarrow linearization of KS equations is useful.
- Linearization can be used in a post-processing step:
 - 1. to estimate the error on QoI: $Q(P) Q(P_*) \approx dQ(P) \cdot R_{Schur}(P)$ up to higher order terms;
 - 2. to refine the obtained solution: $Q(P) dQ(P) \cdot R_{Schur}(P)$ is a better approximation of $Q(P_*)$.
- Implemented by default in DFTK.jl in a simplified framework (PR by Bruno Ploumhans). To be released in the next version.

Perspectives and ideas:

- Metallic systems (positive gap assumption does not hold anymore).
- Other quantities of interest than interatomic forces.
- Fully guaranteed bounds (on the energy, taking into account both SCF and discretization errors, cf. poster by Rafael Lainez and me).

Some references on post-processing techniques:

- E. Cancès, G. Dusson, Y. Maday, B. Stamm, and M. Vohralik. Post-Processing of the Planewave Approximation of Schrödinger Equations. Part I: Linear Operators. IMA Journal of Numerical Analysis 41(4):2423-55 (2021).
- G. Dusson. Post-Processing of the Plane-Wave Approximation of Schrödinger Equations. Part II: Kohn–Sham Models. IMA Journal of Numerical Analysis 41(4):2456-87 (2021).
- E. Cancès, G. Dusson, G Kemlin, and A. Levitt. Practical Error Bounds for Properties in Plane-Wave Electronic Structure Calculations. SIAM Journal on Scientific Computing 44(5):B1312-40 (2022).



Pluto notebook

Merci!











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